

SEMiX 453GB12T4s



Trench IGBT Modules

- SEMiX 453GB12T4s
- SEMiX 453GAL12T4s
- SEMiX 453GAR12T4s

Target Data

Features

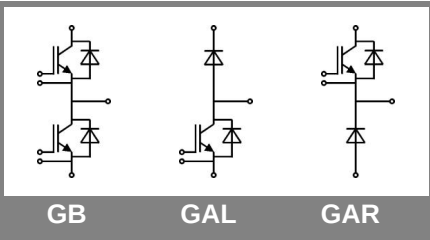
- Homogeneous Si
- Trench = Trenchgate technology
- $V_{CE(sat)}$ with positive temperature coefficient
- High short circuit capability

Typical Applications

- AC inverter drives
- UPS
- Electronic Welding

Remarks

- Case temperature limited to $T_C=125^{\circ}C$ max.
- Product reliability results are valid for $T_J=150^{\circ}C$
- Dynamic values apply to the following combination of resistors:
 $R_{Gon,main}=1,0\Omega$,
 $R_{Goff,main}=1,0\Omega$,
 $R_{G,x}=2,2\Omega$ each,
 $R_{E,x}=0,5\Omega$ each

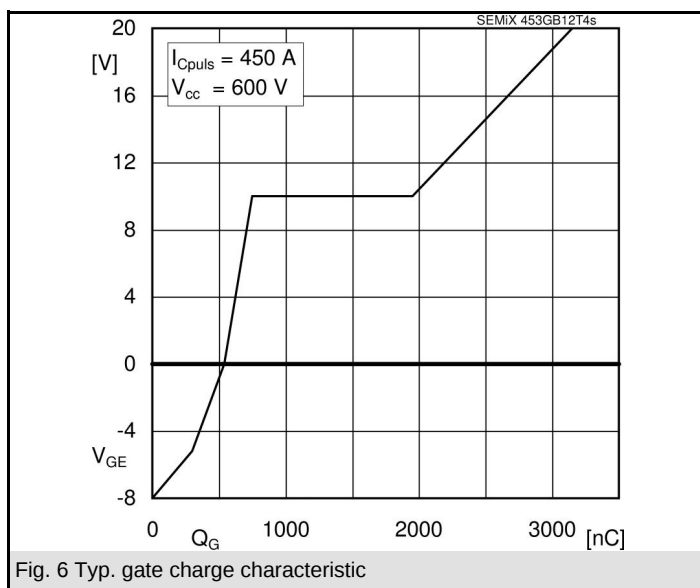
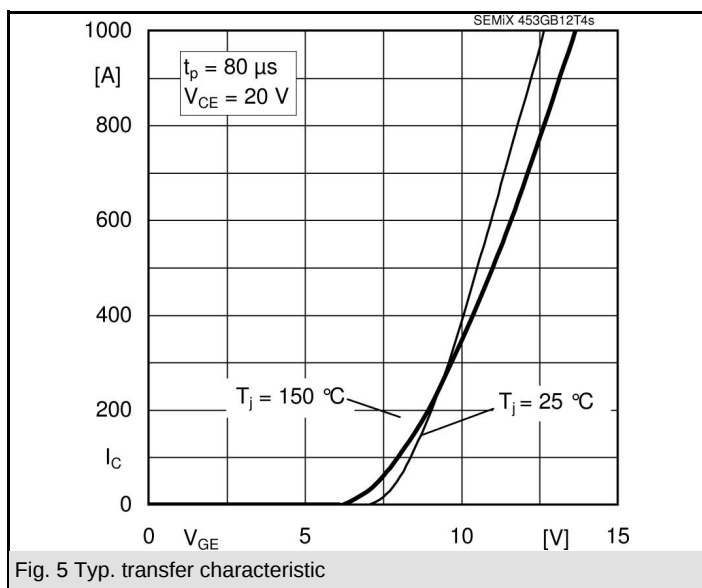
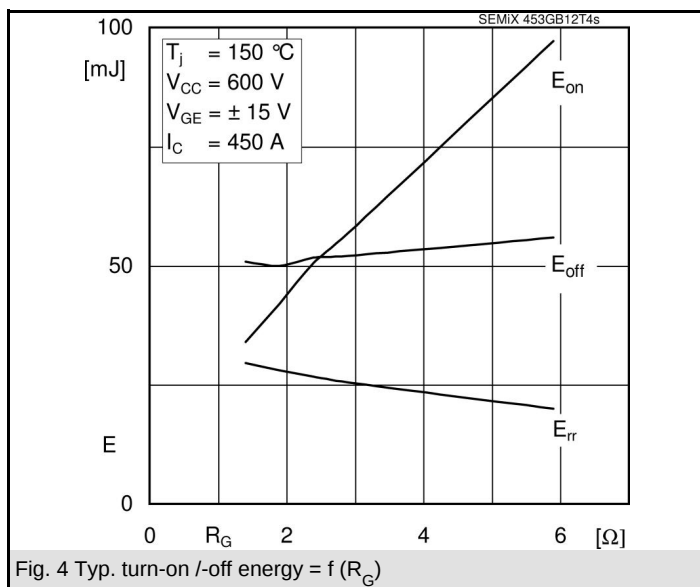
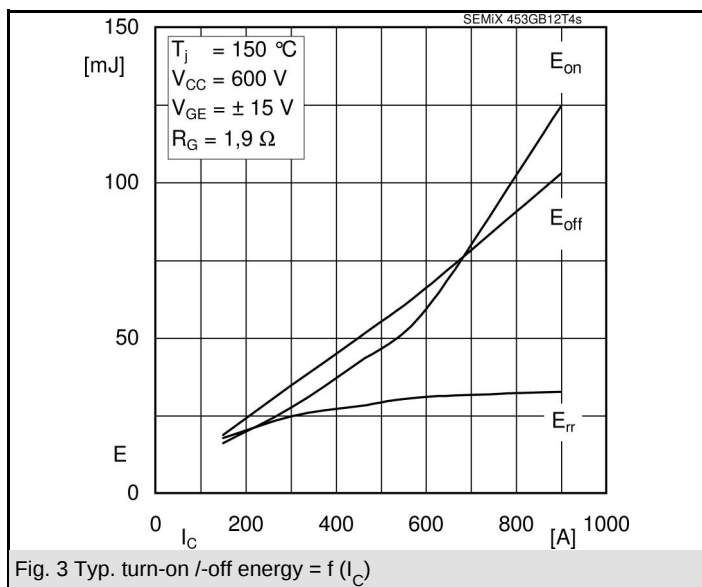
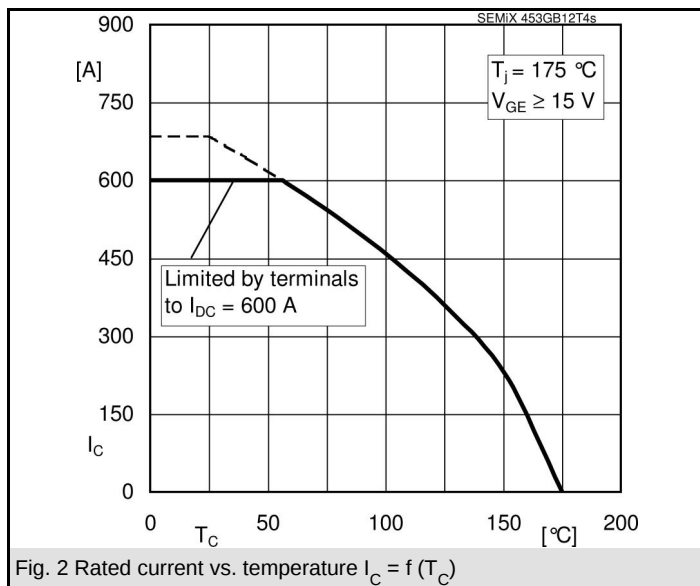
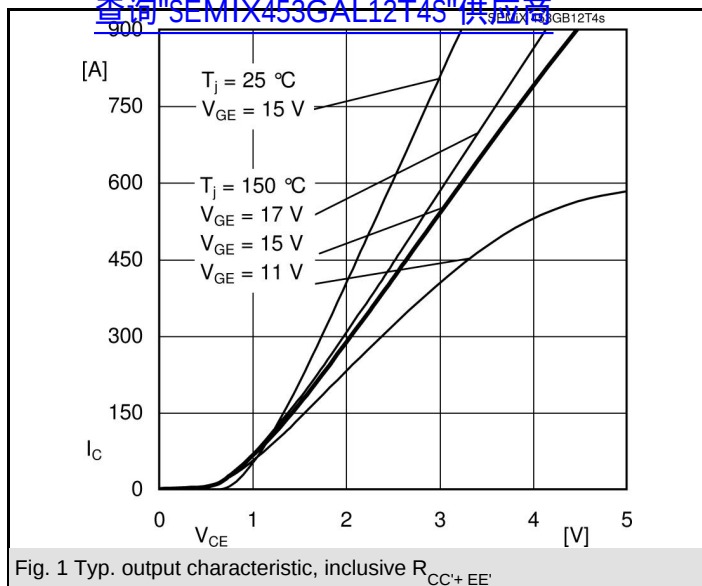


Characteristics					
Symbol	Conditions	min.	typ.	max.	Units
Inverse Diode					
$V_F = V_{EC}$	$I_{Fnom} = 450\text{ A}; V_{GE} = 0\text{ V}$ $T_J = 25^{\circ}C_{chiplev.}$ $T_J = 150^{\circ}C_{chiplev.}$		2,15 2,05	2,45 2,4	V V
V_{F0}	$T_J = 25^{\circ}C$ $T_J = 150^{\circ}C$		1,3 0,9	1,5 1,1	V V
r_F	$T_J = 25^{\circ}C$ $T_J = 150^{\circ}C$		1,9 2,6	2,1 2,9	mΩ mΩ
I_{RRM} Q_{rr} E_{rr}	$I_{Fnom} = 450\text{ A}$ $di/dt = 5000\text{ A}/\mu s$ $V_{GE} = -15\text{ V}; V_{CC} = 600\text{ V}$ $T_J = 150^{\circ}C$		350 70 28		A μC mJ
$R_{th(j-c)D}$	per diode			0,11	K/W
Module					
L_{CE}			20		nH
$R_{CC'+EE'}$	res., terminal-chip $T_{case} = 25^{\circ}C$ $T_{case} = 125^{\circ}C$		0,7 1		mΩ mΩ
$R_{th(c-s)}$	per module		0,04		K/W
M_s	to heat sink (M5)	3		5	Nm
M_t	to terminals (M6)	2,5		5	Nm
w				300	g
Temperature sensor					
R_{100} $B_{100/125}$	$T_C=100^{\circ}C$ ($R_{25}=5\text{ k}\Omega$) $R(T)=R_{100}\exp[B_{100/125}(1/T-1/T_{100})];$ $T[K]$		0,493±5% 3550±2%		kΩ K

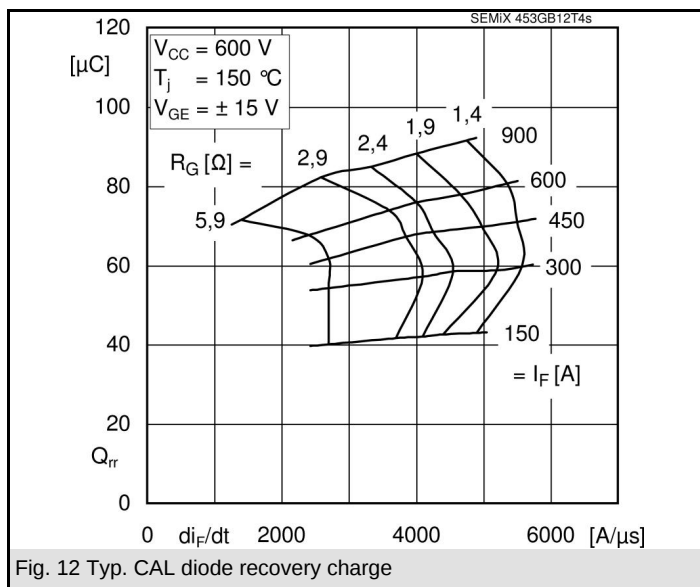
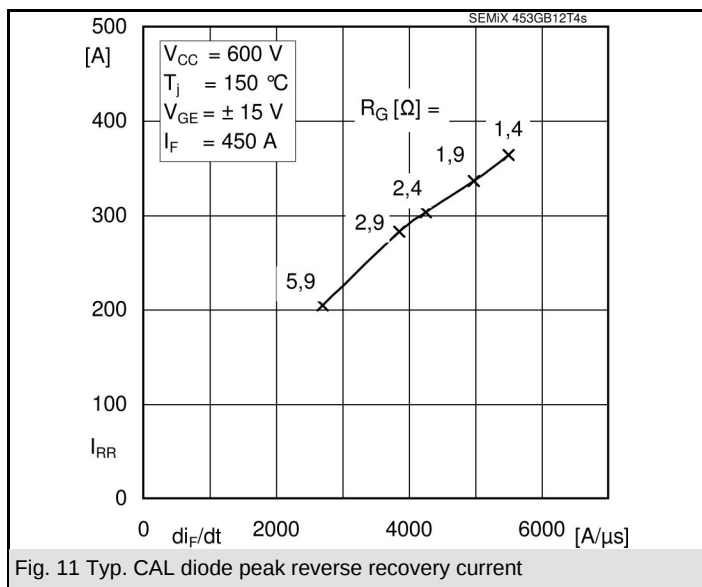
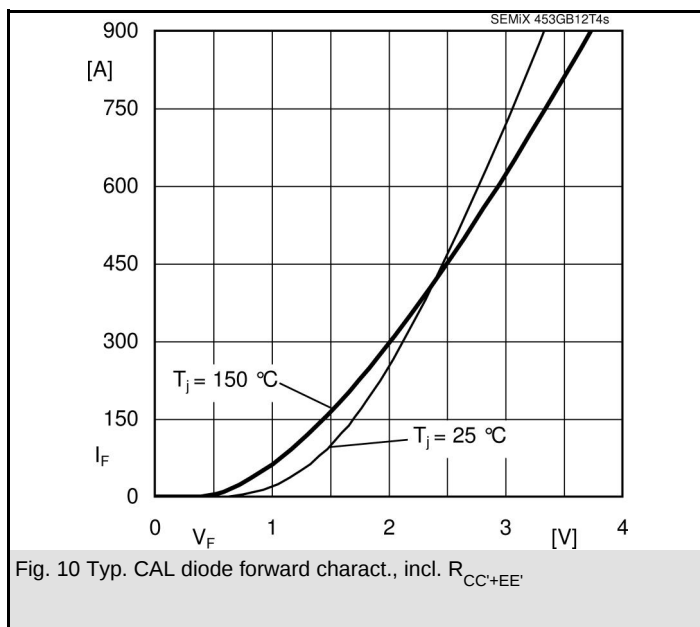
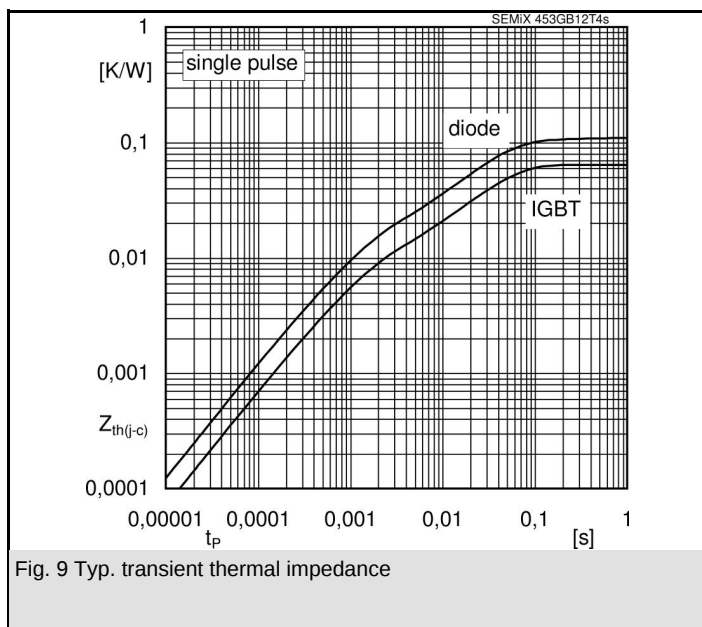
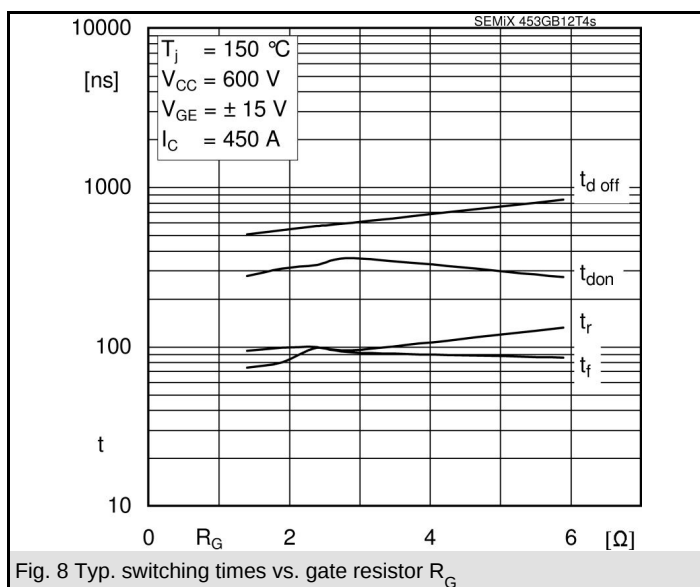
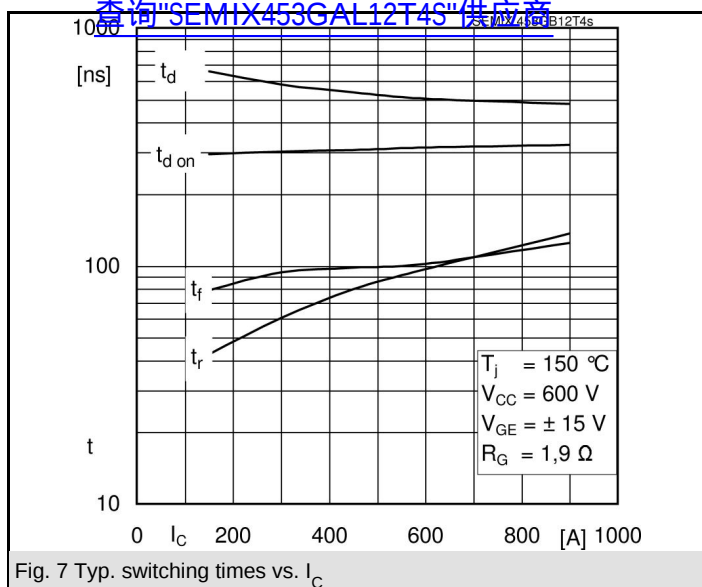
This is an electrostatic discharge sensitive device (ESDS), international standard IEC 60747-1, Chapter IX.

This technical information specifies semiconductor devices but promises no characteristics. No warranty or guarantee expressed or implied is made regarding delivery, performance or suitability.

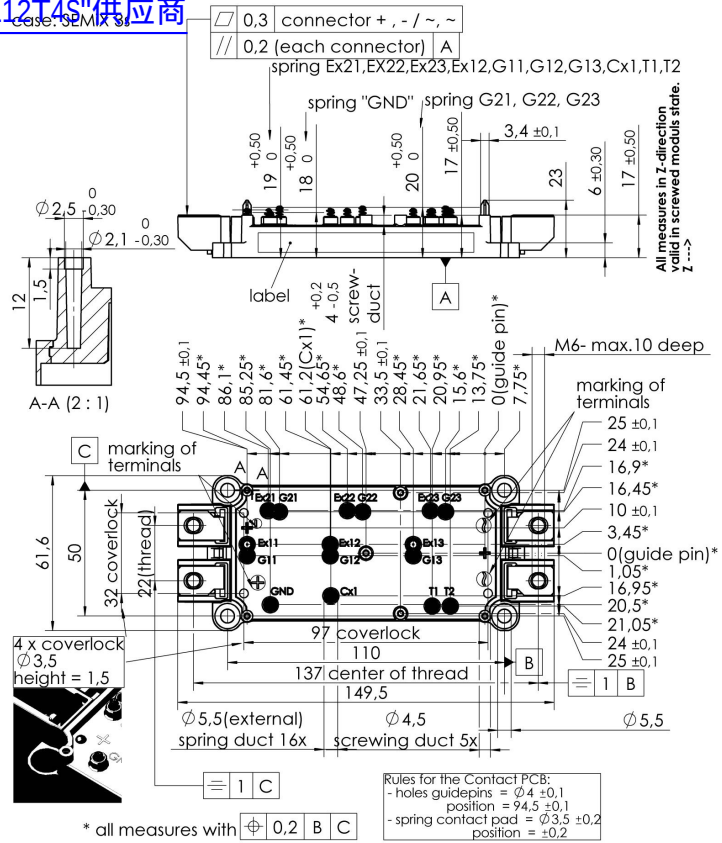
查询"SEMiX453GB12T4S"供应商



查询"SEMiX453GB12T4s"供应商



查询"SEMIX453GAL12T4S"供应商



Case SEMiX 3s

